

IR2108(4) (S)

HALF-BRIDGE DRIVER

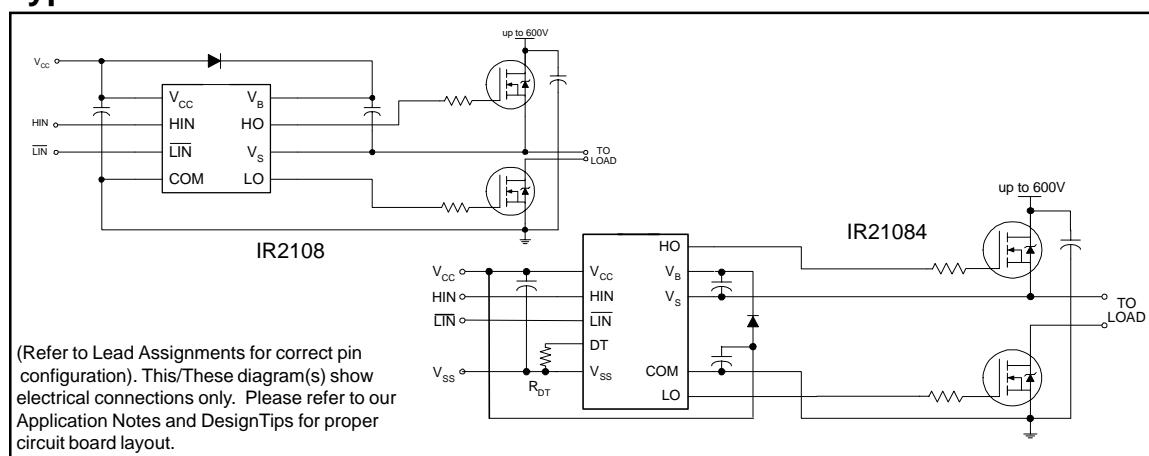
Features

- Floating channel designed for bootstrap operation
Fully operational to +600V
Tolerant to negative transient voltage
dV/dt immune
- Gate drive supply range from 10 to 20V
- Undervoltage lockout for both channels
- 3.3V, 5V and 15V input logic compatible
- Cross-conduction prevention logic
- Matched propagation delay for both channels
- High side output in phase with HIN input
- Low side output out of phase with LIN input
- Logic and power ground +/- 5V offset.
- Internal 540ns dead-time, and
programmable up to 5us with one
external R_{DT} resistor (IR21084)
- Lower di/dt gate driver for better
noise immunity

Description

The IR2108(4)(S) are high voltage, high speed power MOSFET and IGBT drivers with dependent high and low side referenced output channels. Proprietary HVIC and latch immune CMOS technologies enable ruggedized monolithic construction. The logic input is compatible with standard CMOS or LSTTL output, down to 3.3V logic. The output drivers feature a high pulse current buffer stage designed for minimum driver cross-conduction. The floating channel can be used to drive an N-channel power MOSFET or IGBT in the high side configuration which operates up to 600 volts.

Typical Connection



IR2108(4) (S)

International
Rectifier

Absolute Maximum Ratings

Absolute maximum ratings indicate sustained limits beyond which damage to the device may occur. All voltage parameters are absolute voltages referenced to COM. The thermal resistance and power dissipation ratings are measured under board mounted and still air conditions.

Symbol	Definition	Min.	Max.	Units
V_B	High side floating absolute voltage	-0.3	625	V
V_S	High side floating supply offset voltage	$V_B - 25$	$V_B + 0.3$	
V_{HO}	High side floating output voltage	$V_S - 0.3$	$V_B + 0.3$	
V_{CC}	Low side and logic fixed supply voltage	-0.3	25	
V_{LO}	Low side output voltage	-0.3	$V_{CC} + 0.3$	
DT	Programmable dead-time pin voltage (IR21084 only)	$V_{SS} - 0.3$	$V_{CC} + 0.3$	
V_{IN}	Logic input voltage (HIN & LIN)	$V_{SS} - 0.3$	$V_{CC} + 0.3$	
V_{SS}	Logic ground (IR21084 only)	$V_{CC} - 25$	$V_{CC} + 0.3$	
dV_S/dt	Allowable offset supply voltage transient	—	50	V/ns
P_D	Package power dissipation @ $T_A \leq +25^\circ\text{C}$	(8 lead PDIP)	—	1.0
		(8 lead SOIC)	—	0.625
		(14 lead PDIP)	—	1.6
		(14 lead SOIC)	—	1.0
R_{thJA}	Thermal resistance, junction to ambient	(8 lead PDIP)	—	125
		(8 lead SOIC)	—	200
		(14 lead PDIP)	—	75
		(14 lead SOIC)	—	120
T_J	Junction temperature	—	150	$^\circ\text{C}$
T_S	Storage temperature	-50	150	
T_L	Lead temperature (soldering, 10 seconds)	—	300	

Recommended Operating Conditions

The Input/Output logic timing diagram is shown in figure 1. For proper operation the device should be used within the recommended conditions. The V_S and V_{SS} offset rating are tested with all supplies biased at 15V differential.

Symbol	Definition	Min.	Max.	Units
V_B	High side floating supply absolute voltage	$V_S + 10$	$V_S + 20$	V
V_S	High side floating supply offset voltage	Note 1	600	
V_{HO}	High side floating output voltage	V_S	V_B	
V_{CC}	Low side and logic fixed supply voltage	10	20	
V_{LO}	Low side output voltage	0	V_{CC}	
V_{IN}	Logic input voltage	IR2108	COM	
		IR21084	V_{SS}	
DT	Programmable dead-time pin voltage (IR21084 only)	V_{SS}	V_{CC}	
V_{SS}	Logic ground (IR21084 only)	-5	5	$^\circ\text{C}$
T_A	Ambient temperature	-40	125	

Note 1: Logic operational for V_S of -5 to +600V. Logic state held for V_S of -5V to $-V_{BS}$. (Please refer to the Design Tip DT97-3 for more details).

Dynamic Electrical Characteristics

V_{BIAS} (V_{CC}, V_{BS}) = 15V, V_{SS} = COM, C_L = 1000 pF, T_A = 25°C, DT = V_{SS} unless otherwise specified.

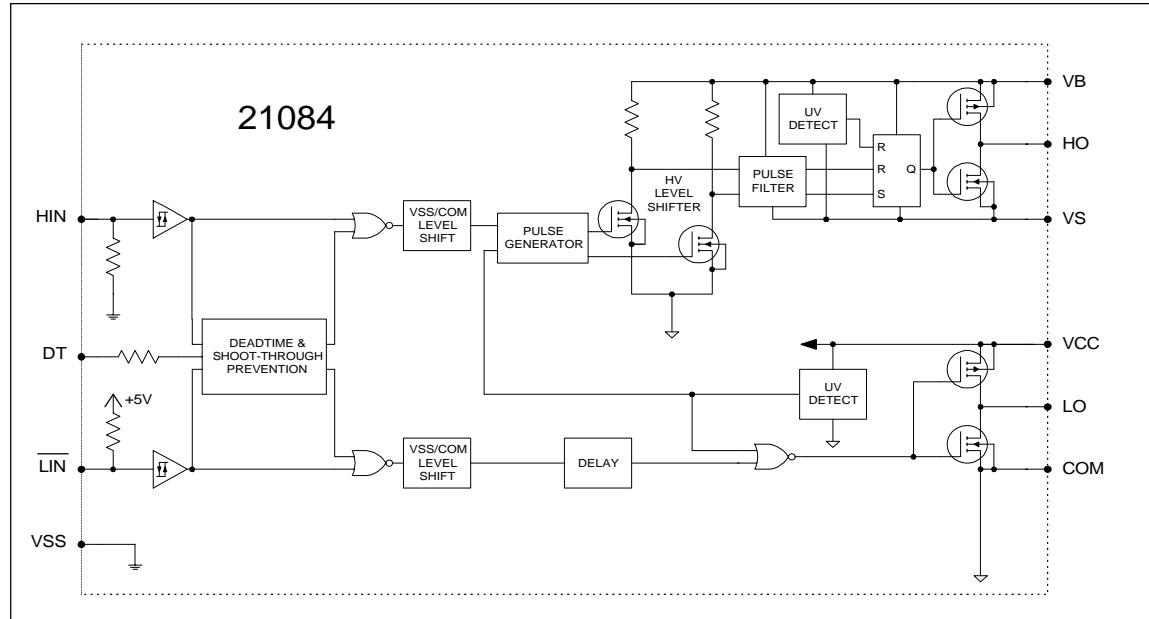
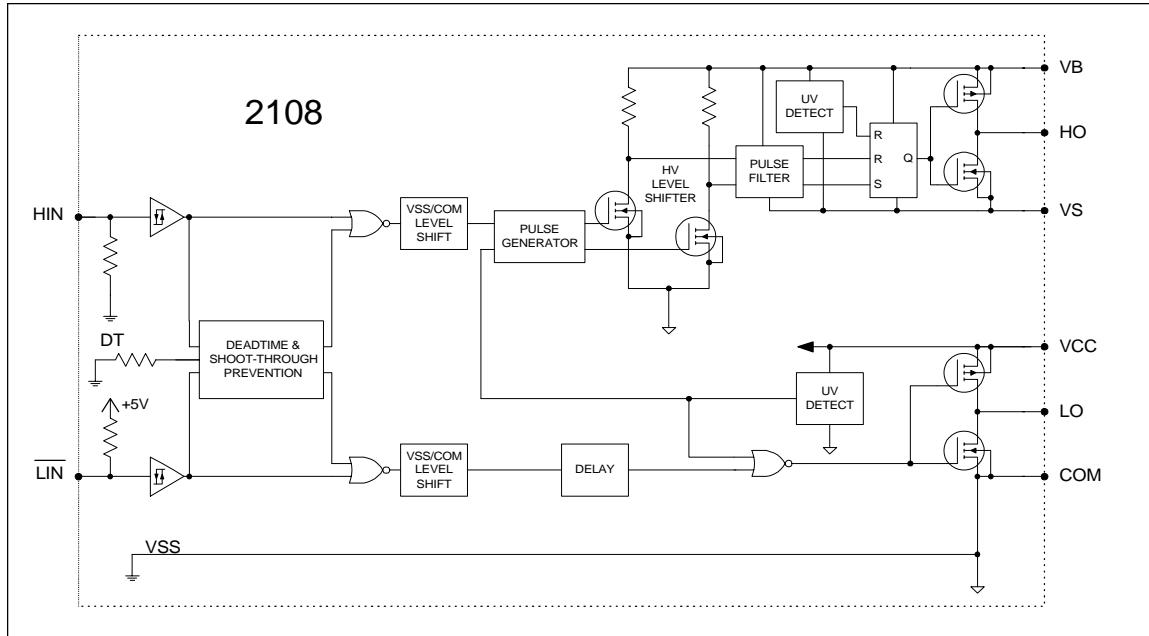
Symbol	Definition	Min.	Typ.	Max.	Units	Test Conditions
t _{on}	Turn-on propagation delay	—	220	300	nsec	V _S = 0V
t _{off}	Turn-off propagation delay	—	200	280		V _S = 0V or 600V
MT	Delay matching t _{on} - t _{off}	—	0	30		
t _r	Turn-on rise time	—	150	220		V _S = 0V
t _f	Turn-off fall time	—	50	80		V _S = 0V
DT	Deadtime: LO turn-off to HO turn-on(DT _{LO-HO}) & HO turn-off to LO turn-on (DT _{HO-LO})	400	540	680		RDT= 0
MDT	Deadtime matching = DT _{LO-HO} - DT _{HO-LO}	4	5	6	usec	RDT = 200k (IR21084)
		—	0	60	nsec	RDT=0
		—	0	600		RDT = 200k (IR21084)

Static Electrical Characteristics

V_{BIAS} (V_{CC}, V_{BS}) = 15V, V_{SS} = COM, DT= V_{SS} and T_A = 25°C unless otherwise specified. The V_{I_L}, V_{I_H} and I_{I_N} parameters are referenced to V_{SS}/COM and are applicable to the respective input leads: HIN and LIN. The V_O, I_O and R_{on} parameters are referenced to COM and are applicable to the respective output leads: HO and LO.

Symbol	Definition	Min.	Typ.	Max.	Units	Test Conditions
V _{I_H}	Logic "1" input voltage for HIN & logic "0" for LIN	2.9	—	—	V	V _{CC} = 10V to 20V
V _{I_L}	Logic "0" input voltage for HIN & logic "1" for LIN	—	—	0.8		V _{CC} = 10V to 20V
V _{O_H}	High level output voltage, V _{BIAS} - V _O	—	0.8	1.4		I _O = 20 mA
V _{O_L}	Low level output voltage, V _O	—	0.3	0.6		I _O = 20 mA
I _{LK}	Offset supply leakage current	—	—	50	μA	V _B = V _S = 600V
I _{QBS}	Quiescent V _{BS} supply current	20	60	150		V _{IN} = 0V or 5V
I _{QCC}	Quiescent V _{CC} supply current	0.4	1.0	1.6	mA	V _{IN} = 0V or 5V RDT=0
I _{I_N₊}	Logic "1" input bias current	—	5	20	μA	HIN = 5V, LIN = 0V
I _{I_N₋}	Logic "0" input bias current	—	1	2		HIN = 0V, LIN = 5V
V _{CCUV+} V _{BSUV+}	V _{CC} and V _{BS} supply undervoltage positive going threshold	8.0	8.9	9.8	V	
V _{CCUV-} V _{BSUV-}	V _{CC} and V _{BS} supply undervoltage negative going threshold	7.4	8.2	9.0		
V _{CCUVH} V _{BSUVH}	Hysteresis	0.3	0.7	—		
I _{O₊}	Output high short circuit pulsed current	120	200	—	mA	V _O = 0V, PW ≤ 10 μs
I _{O₋}	Output low short circuit pulsed current	250	350	—		V _O = 15V, PW ≤ 10 μs

Functional Block Diagram



Lead Definitions

Symbol	Description
HIN	Logic input for high side gate driver output (HO), in phase (referenced to COM for IR2108 and VSS for IR21084)
LIN	Logic input for low side gate driver output (LO), out of phase (referenced to COM for IR2108 and VSS for IR21084)
DT	Programmable dead-time lead, referenced to VSS. (IR21084 only)
VSS	Logic Ground (21084 only)
V _B	High side floating supply
HO	High side gate driver output
V _S	High side floating supply return
V _{CC}	Low side and logic fixed supply
LO	Low side gate driver output
COM	Low side return

Lead Assignments

 8 Lead PDIP	 8 Lead SOIC
IR2108	IR2108S

 14 Lead PDIP	 14 Lead SOIC
IR21084	IR21084S

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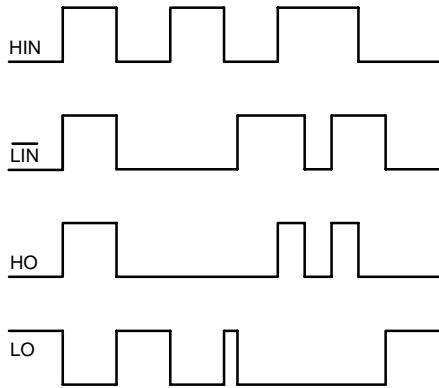


Figure 1. Input/Output Timing Diagram

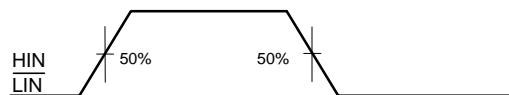
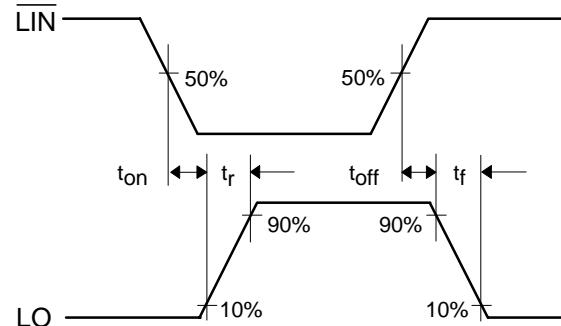


Figure 2. Switching Time Waveform Definitions

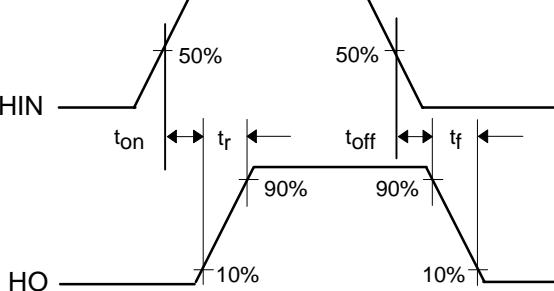
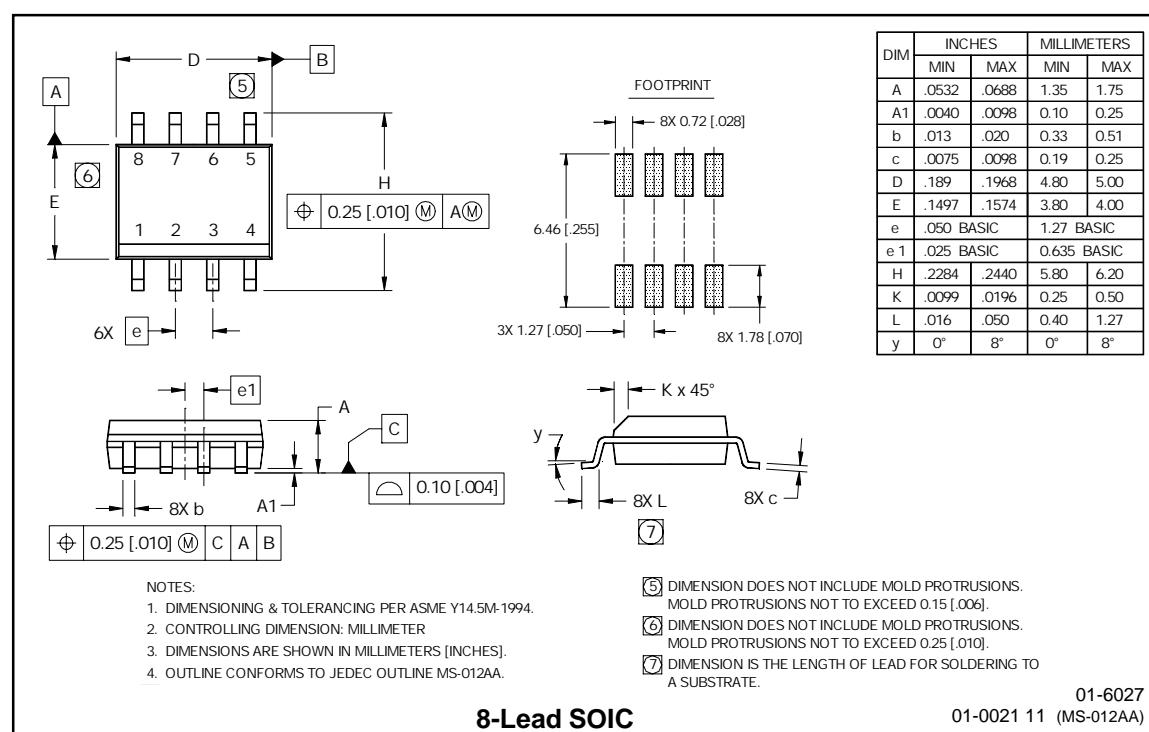
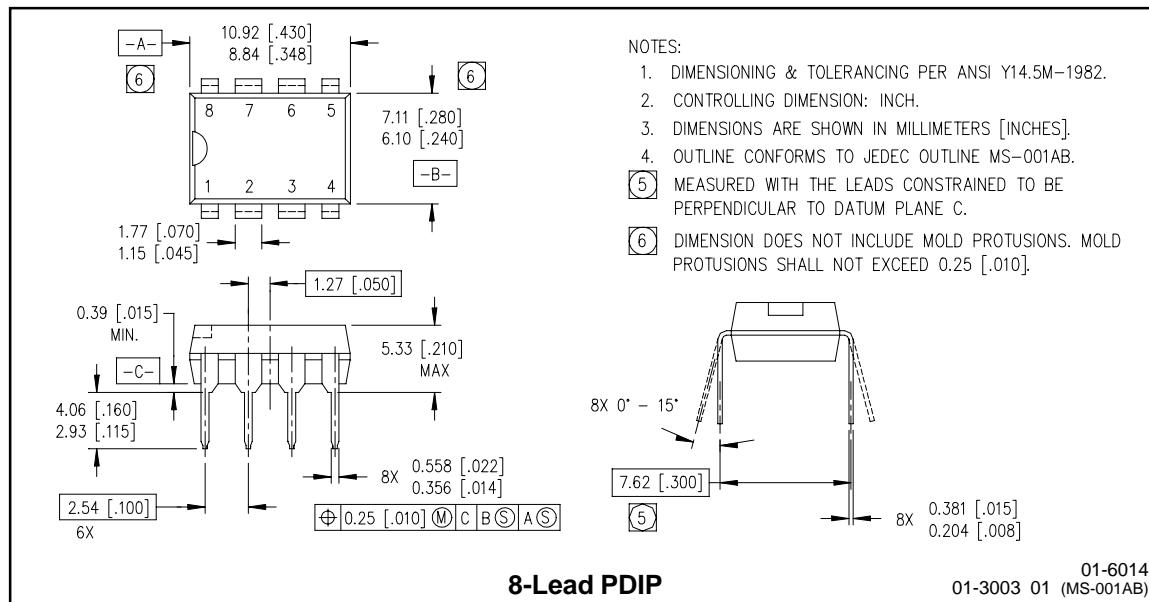


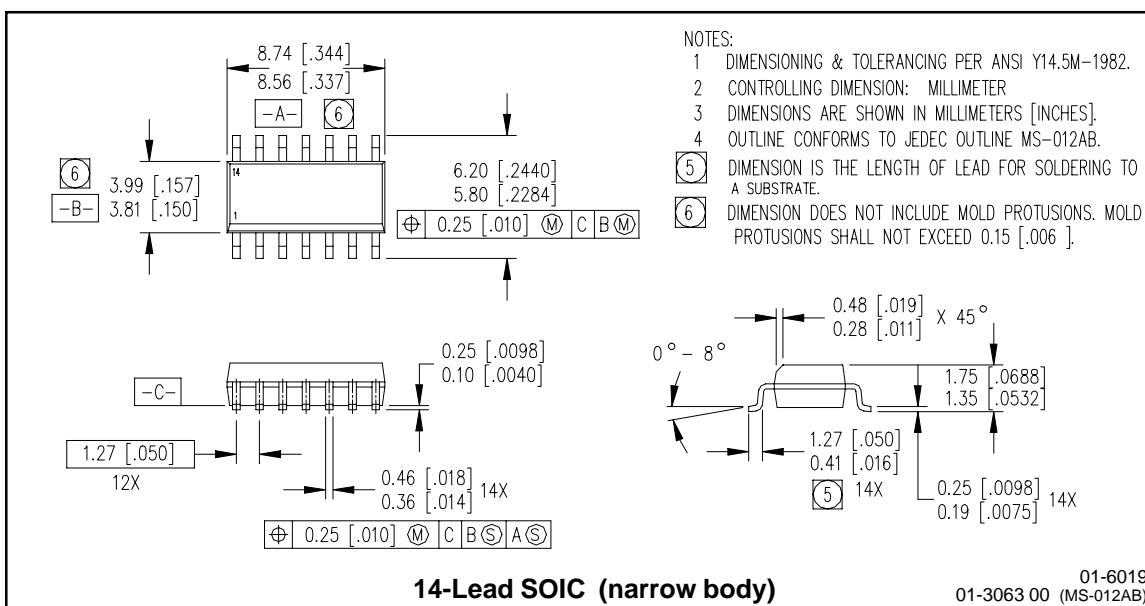
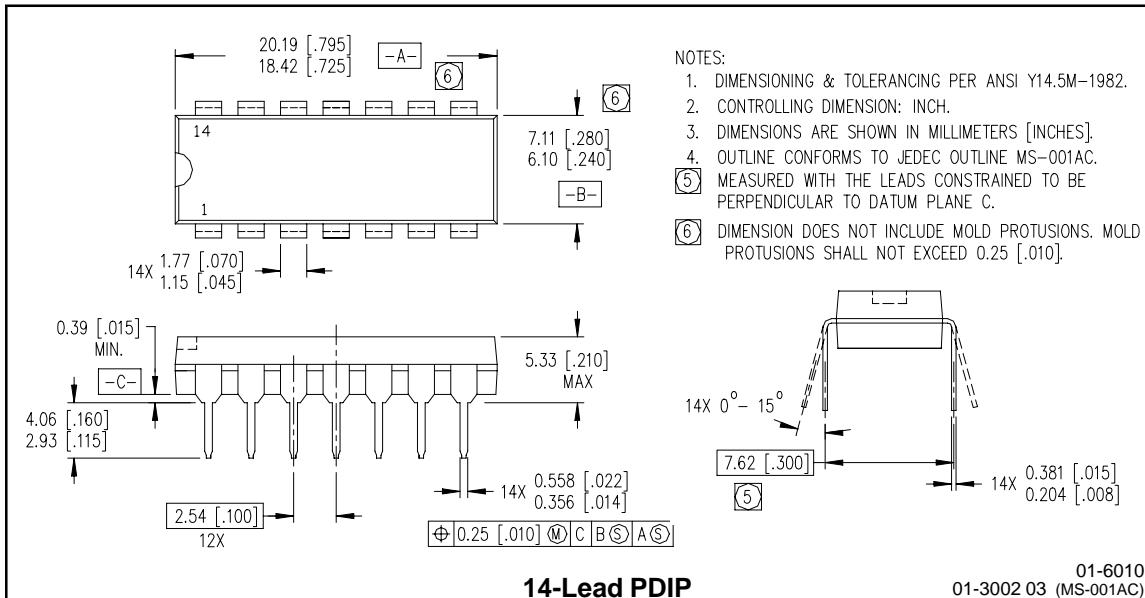
Figure 3. Deadtime Waveform Definitions

Case outlines



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Data and specifications subject to change without notice. 5/13/2002